

# Model

exam n 2 Qns diode ~~2021 2022~~ <sup>Model</sup> 2020 ans

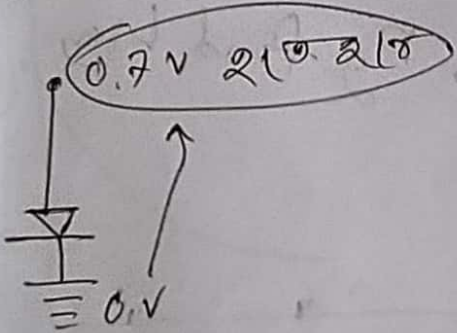
→ const. voltage drop (0.7 V for Si diode)

→ Ideal diode (No voltage drop)

Fwd bias

Reverse bias  $\rightarrow$  Open ckt  $\frac{V}{I} \rightarrow \infty$

4)  $\therefore 0.7 \text{ V drop}$   $I_1 = \frac{5 - V_{ce}}{5} \text{ mA} = \frac{4.3}{5} \text{ mA}$



$$I_2 = \frac{V_a - 0.7}{10} = \frac{V - (-5)}{10} \text{ mA}$$

$$= \frac{(V_a - 0.7) - (-5)}{10} \text{ mA} \quad \left[ \because V = V_a - 0.7 \text{ V} \right]$$

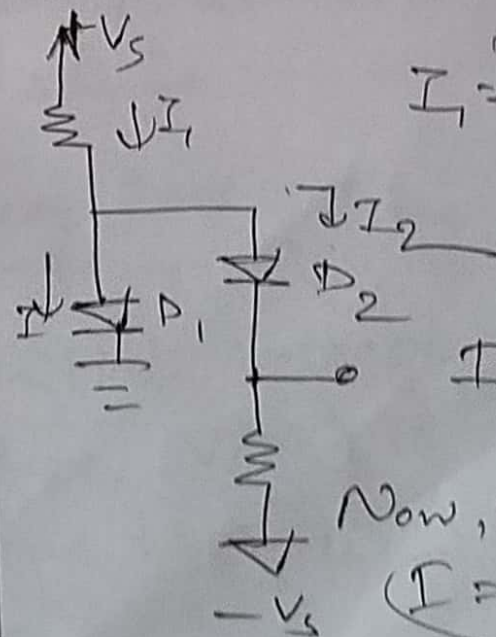
5  $V_a = 0.7 \text{ V}$

$$I_1 = \frac{5 - 0.7}{10} \text{ mA}$$

$$= 0.43 \text{ mA}$$

$$I_2 = \frac{V - (-5)}{5}$$
$$= \frac{0.7 - 0.7 - (-5)}{5}$$
$$= 1 \text{ mA}$$

THINK YOURSELF.



$$I_1 = \frac{V_s - 0.7}{R_1} > 0$$

$$\therefore V_s > 0.7$$

$$T_2 - \frac{V_s}{R_2} > 0$$

Now, for  $D_1, D_2 \rightarrow$  find  $\frac{d}{dt}$

$$(I = I_1 - I_2 > 0)$$

$$\Rightarrow T_1 > T_2$$

$$\Rightarrow \frac{V_3 - 0.7}{R_1} > \frac{V_5}{R_2}$$

$$\Rightarrow \frac{R_2}{R_1} > \frac{V_S}{V_S - 0.7}$$

$$\therefore \frac{R_2}{R_1} > 1$$

$\therefore R_2 > R_1 \rightarrow$  both diodes fwd bias

$R_2$  and,  $I_1 - I_2 < 0 \rightarrow D_1$  reverse bias

$\Rightarrow \boxed{R_2 \leq R_1} \rightarrow D_2$  fwd bias

LO2 online + This note

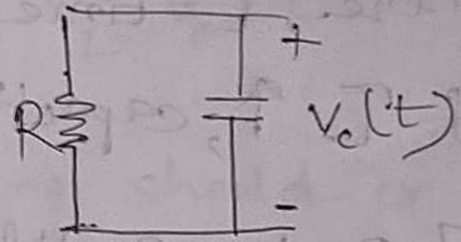
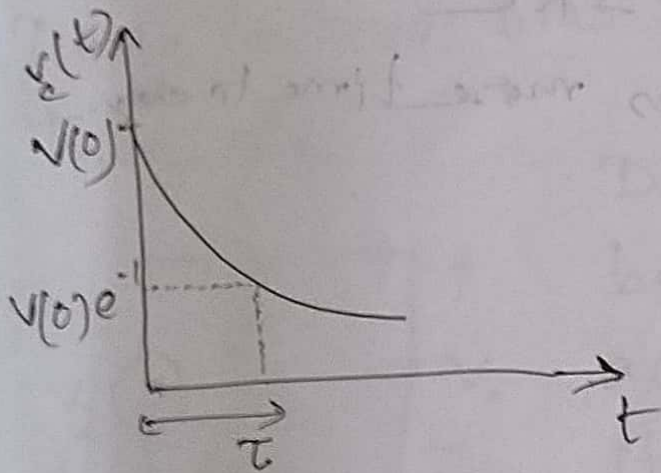
breakdown  $\begin{cases} \rightarrow \text{Zener Breakdown} \\ \rightarrow \text{Avalanche} \end{cases}$



Time const. of an R-C Ckt.

If a capacitor has initial voltage  $V(0)$  and it has a resistor across it, then capacitor voltage,

$$V_c(t) = V(0)e^{-t/\tau}$$



When  $t = \tau$ ,  $V_c(t) = V(0)e^{-1}$

time const  $\uparrow$  capacitor charge 2 to time  $\uparrow$   
(also  $\sim$  discharge  $\sim$  time  $\uparrow$ )  
" "  $\uparrow$  voltage decay slow, time

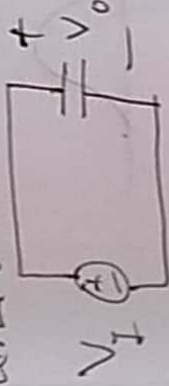
If a capacitor has initial voltage  $V(0)$  and a voltage src with voltage  $V(\infty)$  is connected to the capacitor at time  $t=0$ , then capacitor voltage,  $V_c(t) = V(0)e^{-t/\tau} + V(\infty)(1 - e^{-t/\tau})$





Diode in fwd. bias when  $V_T - V_0 > 0$

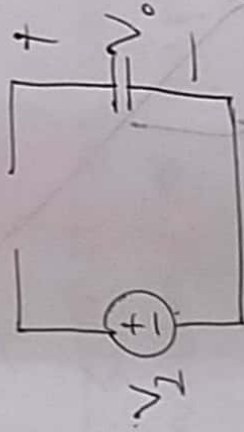
Then ckt.



charging occurs

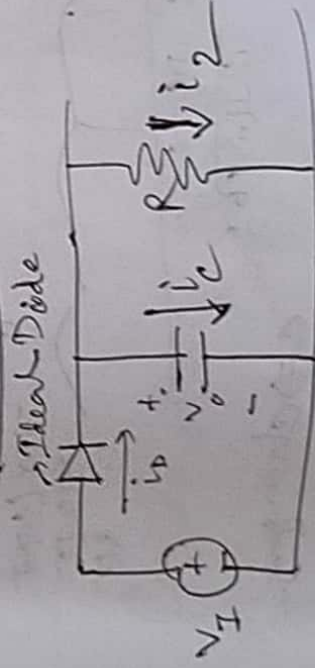
Diode in rev. bias when  $V_T - V_0 < 0$

Then ckt.

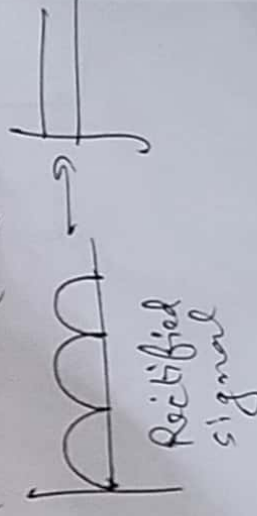


Discharging should occur, but there is no resistor across capacitor so that it can discharge i.e.  $R = \infty$ , so  $\tau = \infty$ ,  $\therefore$  capacitor holds its voltage indefinitely

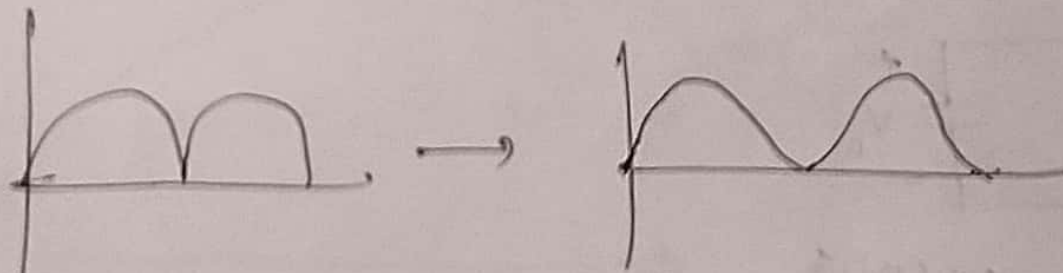
~~Peak~~ Peak Rectifier with Load Resistance:



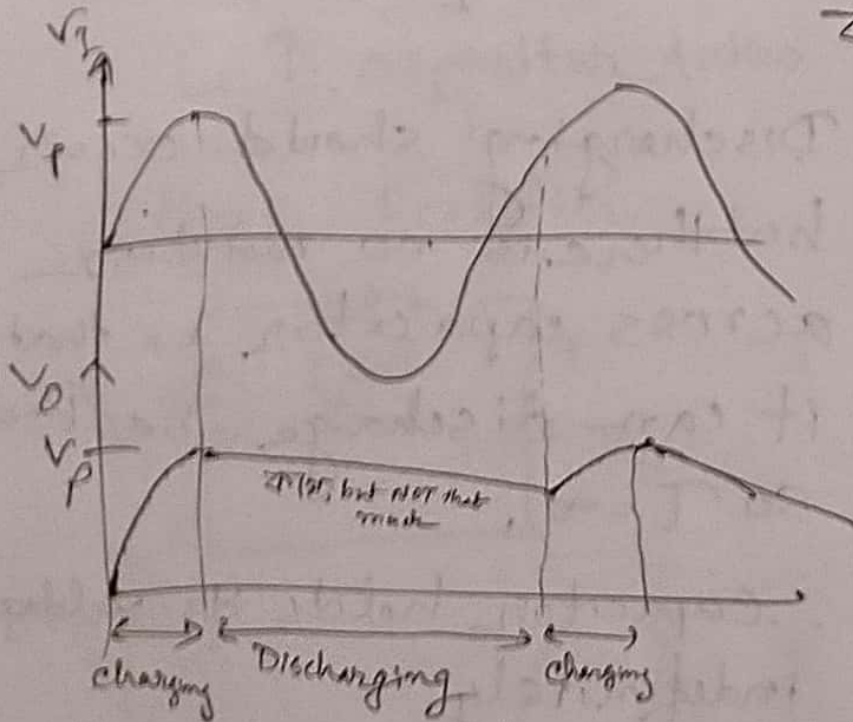
capacitor stores main energy  $\therefore$



But, what we get is,

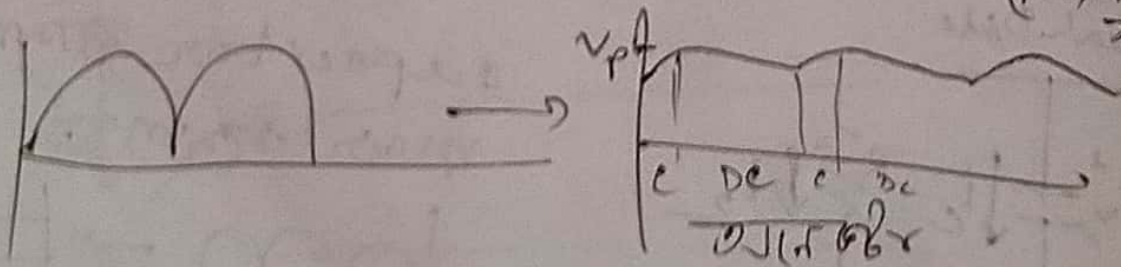


~~$2\tau_n$  time to di~~  $2\tau_n$  (time to discharge)  $\gg T$   
 ২টি সময়, বেশি

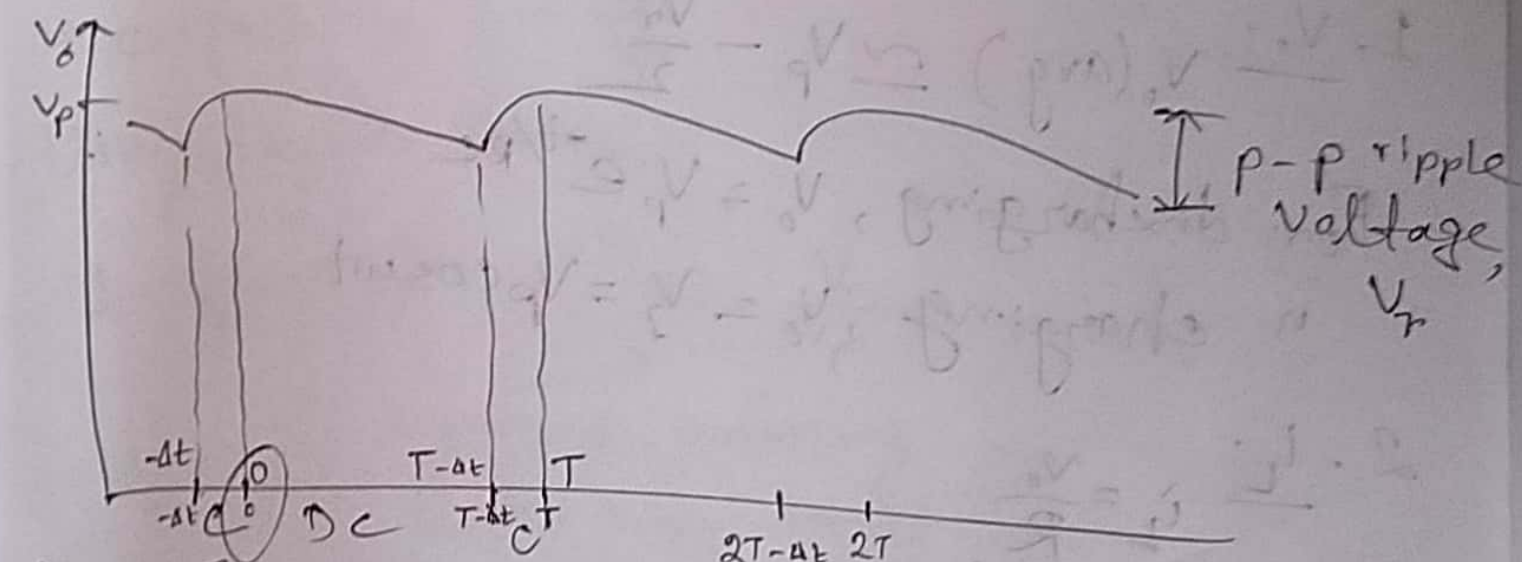


How to achieve that?  
 $\tau \uparrow$  (time to  $\uparrow$ )  
 needs  $\tau$  (discharge target)  
 নীচের (RC) কত সময়  
 সময় (অবস্থা)  
 স্থির  
 ২৫

Now we get

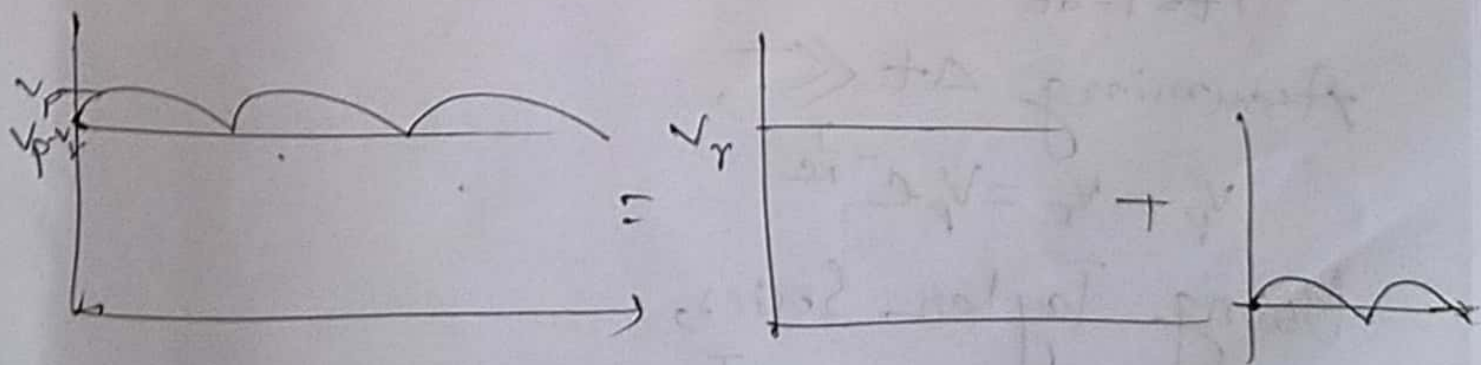


$C \Rightarrow$  charging...  
 $DC \Rightarrow$  Discharging...



Graph of rectifier output voltage  $V_o$  vs time  $t$ .

The DC voltage  $V_{dc}$  and the AC voltage  $V_r$  are superimposed on each other.  $V_r$  is the ripple voltage.



Conduction interval: Time Duration of a cycle when Diode conducts. ( $\Delta t$ )



**Graphene : I'm the most  
flexible material**





$$1. \underline{V_o}: V_o(\text{avg}) \approx V_p - \frac{V_r}{2}$$

For discharging,  $V_o = V_p e^{-t/RC}$   
 in charging,  $V_o = V_p = V_p \cos \omega t$

$$2. \underline{i_L}: i_L = \frac{V_o}{R}$$

$$i_L(\text{avg}) = \frac{V_o(\text{avg})}{R} = \frac{V_p - \frac{1}{2}V_r}{R} \approx \frac{V_p}{R} = I_L$$

$$i_L(\text{peak}) = \frac{V_o(\text{peak})}{R} = \frac{V_p}{R} = I_L$$

$$3. \underline{V_r}: V_o|_{t=T-\Delta t}$$

$$= V_p - V_r = V_p e^{-\frac{T-\Delta t}{RC}}$$

Assuming  $\Delta t \ll T$ ,

$$V_p - V_r = V_p e^{-\frac{T}{RC}}$$

Using Taylor Series,

$$V_p - V_r = V_p \left(1 - \frac{T}{RC}\right)$$

$$V_r = V_p \frac{T}{RC} = \frac{V_p}{fRC} = \frac{I_L}{fC}$$

$$4. \underline{\Delta t}: V_o|_{t=-\Delta t} = V_p - V_r = V_p \cos(-\omega \Delta t) = V_p \cos(\omega \Delta t)$$

$$\Rightarrow \cos(\omega \Delta t) = 1 - \frac{V_r}{V_p}$$

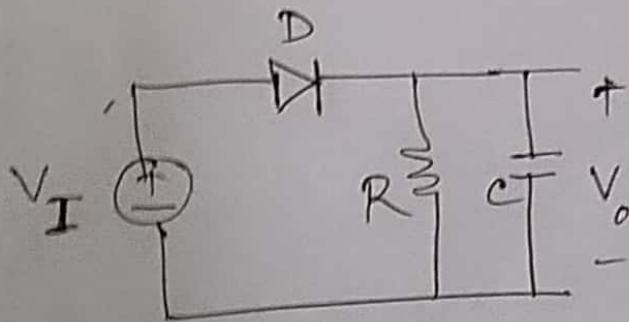
Using Taylor Series,

$$1 - \frac{1}{2}(\omega \Delta t)^2 + \dots = 1 - \frac{V_r}{V_p}$$

ignored assuming  
 $\omega \Delta t$  very small

$$\therefore \omega \Delta t = \sqrt{\frac{2V_r}{V_p}}$$

5.





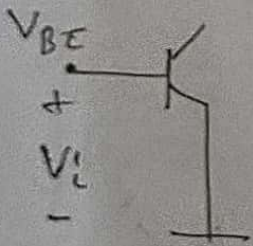
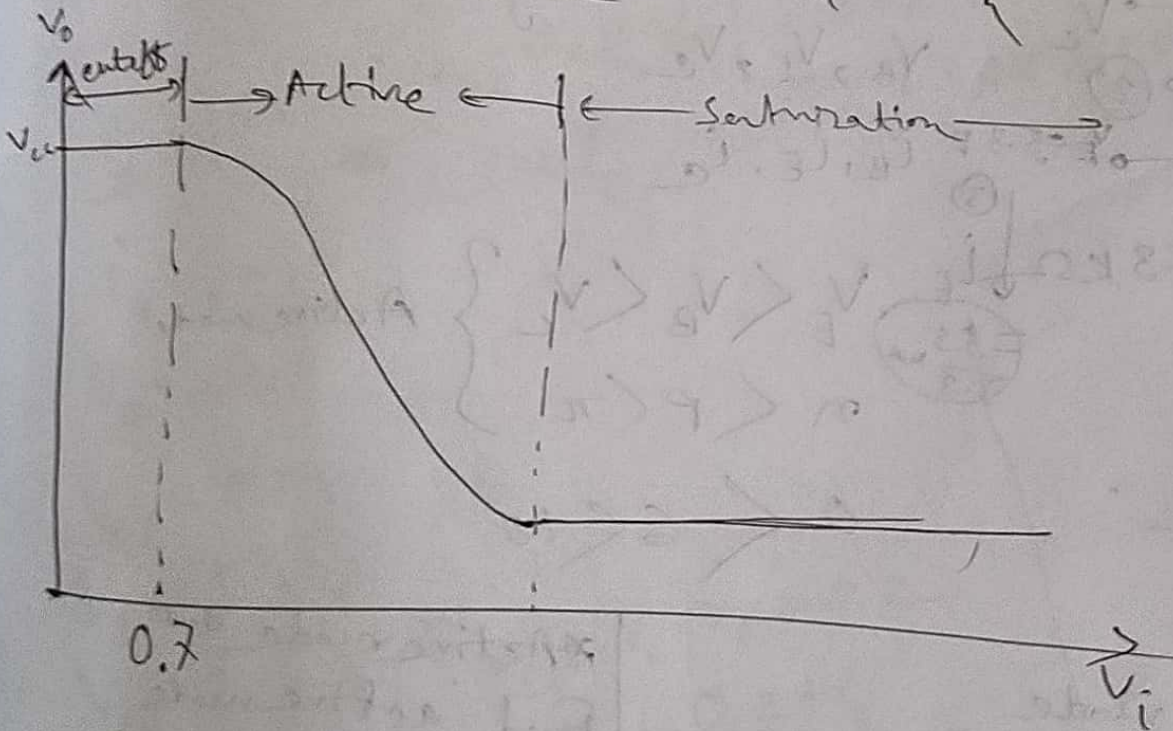
# BJT

L1  $\rightarrow$  I-V characteristics  $\rightarrow$  Input  $\rightarrow$  Output

$V_{CC}$   $\rightarrow$  src collector 40  $\mu$ m  $\rightarrow$  connected

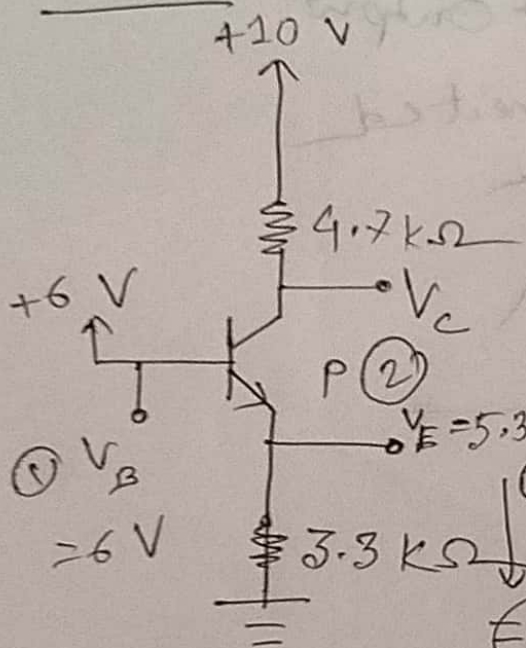
$V_{BB}$   $\rightarrow$  n base " " " "

$V_{EE}$   $\rightarrow$  n Emitter " " " "



# BJT Ckt. at DC

Pr 1:



Calculate all node voltages and current.

For active mode assume  $\beta = 100$

$V_B, V_E, V_C$

$I_B, I_E, I_C$

$V_E < V_B < V_C$  } Active mode  
 $n < p < n$

$0 < \beta < 10$

Assume, active mode

$V_{BE} = 0.7V$  [  $\because$  B-E in fwd. bias ]

$$I_E = \frac{5.3}{3.3} = 1.64 \text{ mA}$$

$$I_C = \alpha I_E = \frac{\beta}{1+\beta} I_E$$

$$\beta = \frac{I_C}{I_B} \Rightarrow I_B = \frac{I_C}{\beta}$$

Active mode Fwd. active mode

$$33 \overline{) 53} \begin{matrix} 1.6 \\ 33 \\ \hline 200 \end{matrix}$$

$$V_C = 10 - 4.7 I_C = 2.48V$$

we got  $\rightarrow V_E < V_B < V_C$   
 $5.3 < 6 < 2.48$

$\therefore$  Assumption wrong



Assuming, Saturation mode

$$V_E < V_B < V_C$$

$$\Rightarrow n < p < n$$

Assump: for sat. mode:

$$V_{CE_{sat}} = 0.2 \text{ V} \quad [2 \text{ B62 find bias } \rightarrow \text{ mode}]$$

~~$$i_E = \beta i_B, \quad i_C = \alpha i_E$$~~

$$i_E = i_B + i_C$$

$$V_B = 6 \text{ V}$$

$$V_{BE} = 0.7 \text{ V}$$

$$V_E = 5.3 \text{ V}$$

$$V_C = 5.5 \text{ V} \quad \left[ \because V_{CE} = V_C - V_E = 0.2 \right]$$

$$V_C = 0.2 + V_E$$

$$= (0.2 + 5.3) \text{ V}$$

$$i_E = \frac{5.3}{3.3} = 1.6 \text{ mA} \quad = \boxed{5.5 \text{ V}}$$

$$i_C = \frac{10 - 5.5}{4.7} = 0.96 \text{ mA}$$

$$i_B = i_E - i_C = 0.64 \text{ mA}$$

$$\beta_{\text{forced}} = \frac{i_C}{i_B} = \frac{0.96}{0.64} = 1.5$$

$\therefore$  sat. mode  $\beta$  (बलित  $\beta$ ) (उपरोक्त मानों पर)

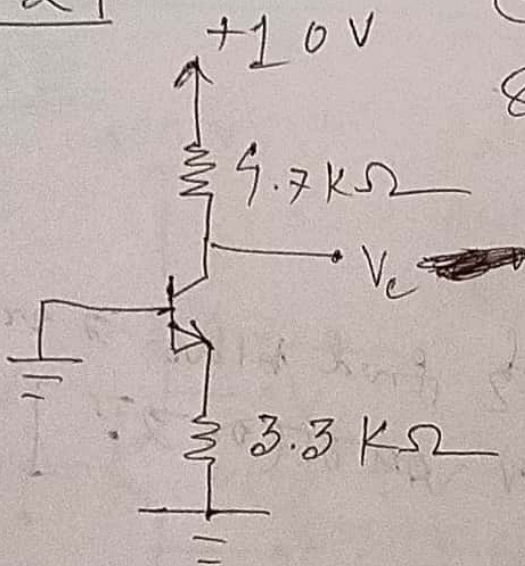


Pr 21:

Calculate all node voltages & current.

For active mode, assume

$$\beta = 100.$$



Ans:  $V_E < V_B < V_C$   
n

\* Assumption 70320  
+10V  
0V  
0V

$V_E$	$V_B$	$V_C$
n	p	n
0	0	10
Rev	Rev	

\* Active 7720  
-ve error:-

7720 7720,

7720 current  
direction 7720  
assumption check  
7720 7720.

∴ let's assume cut-off mode

$$I_E = I_B = I_C = 0 \text{ A}$$

$$V_C = +10 \text{ V}$$

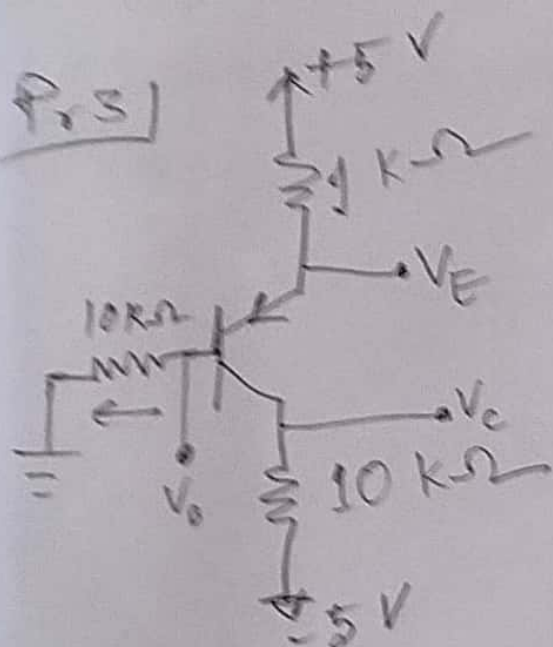
$$V_B = 0 \text{ V}$$

$$V_E = 0 \text{ V}$$

Pr 31



P. 3]



Calculate all node voltages and current.  
For active mode, assume  $\beta = 100$

Ans: Assuming saturation mode,  
 $V_{CE_{sat}} = 0.2V$

⇒ Assuming active mode:  
 $i_B$  very small ( $\mu A$  range)  $\rightarrow i_B \approx 0$

$$i_E = \frac{5 - 0.7}{1} = 4.3 \text{ mA}$$

$$\therefore V_B \approx 0V$$

$$V_E = 0.7V [\because V_{BE} \approx 0.7V]$$

$$\therefore i_C \approx i_E [\because i_B \approx 0]$$

$$\therefore V_C = 10i_C - 5$$

$$= 43 - 5 = 38V$$

Now, E B C

p n p

0.7 0 38

End. End.

∴ Assumption was wrong

~~Ans~~

Assume saturation mode

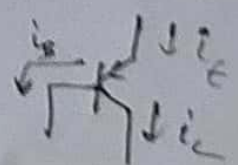
$$V_{EC_{sat}} = 0.2V$$

$$V_{BE} = 0.7V$$

$$i_E = i_B + i_C$$

$$i_C = \frac{5 - 0.2}{1k\Omega} = (5 - V_E) \text{ mA}$$

Current dir.

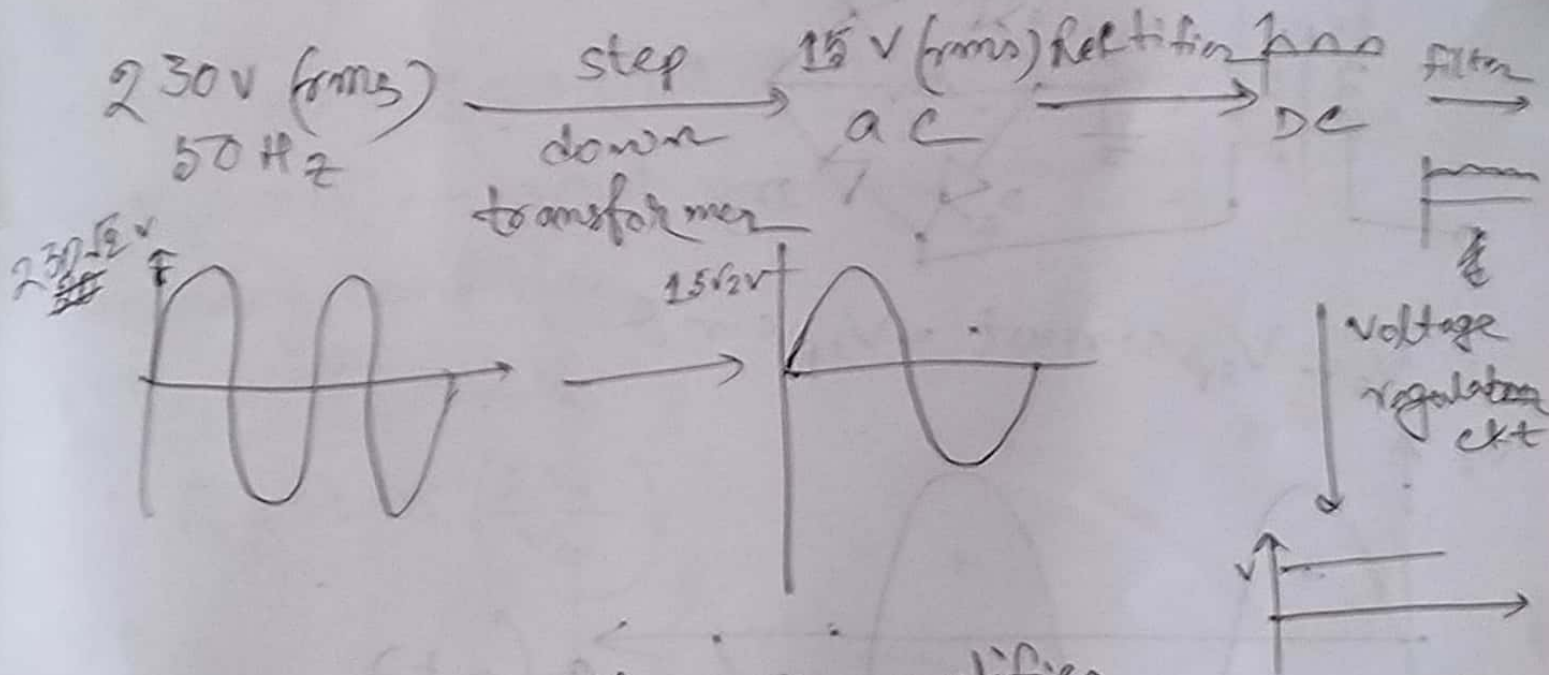


$$5 - (V_B + 0.7)$$

$$= \frac{V_B}{10} + \frac{V_B + 0.5 + 5}{10} \left[ \because i_E = i_B + i_C \right]$$

4.

# Rectifier



Rectifier  $\rightarrow$  Half-wave rectifier  
 Rectifier  $\rightarrow$  Full-wave

Center-tapped  
 Bridge

## Rectifier:

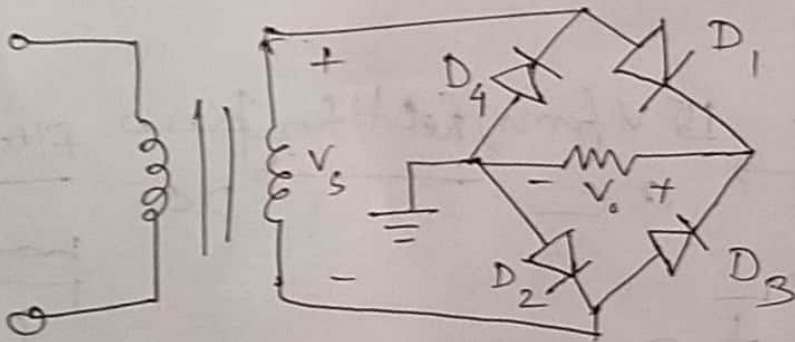
specs:

1. peak current  $<$  diode current rating
2. peak inverse voltage (PIV)  $<$  diode breakdown voltage
3. Avg output voltage
4. Conduction angle

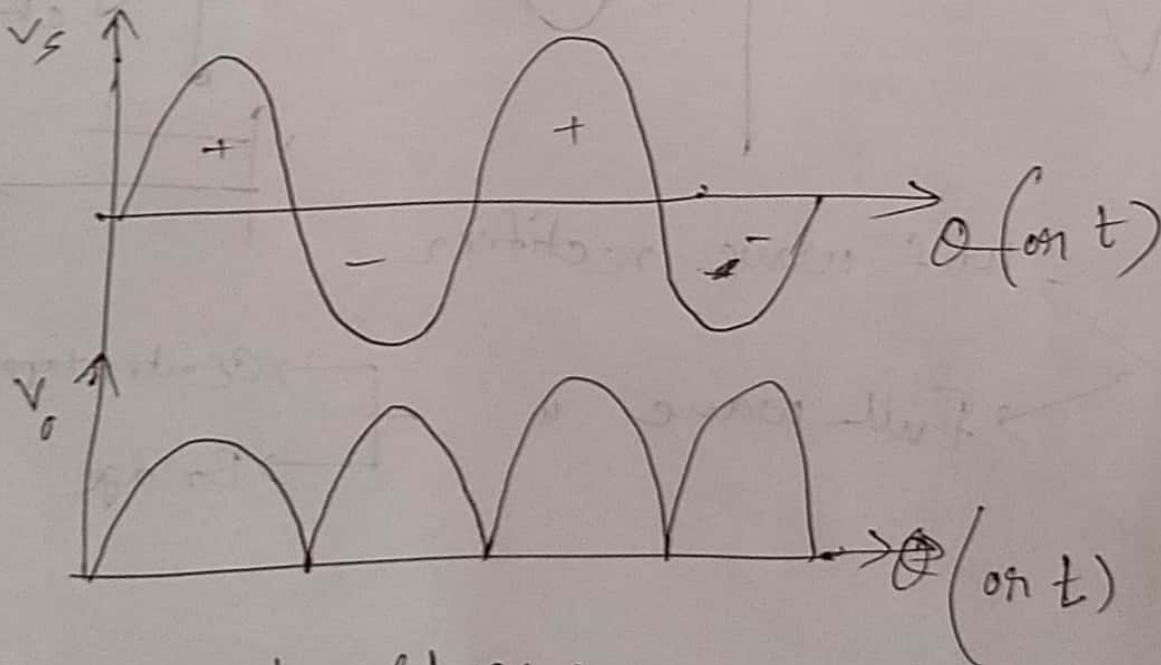


2

## Bridge Rectifier



$$V_s = V_{sp} \sin \omega t = V_{sp} \sin \theta$$



output voltage:

Assume there is a voltage drop  $V_D$  across diode in Fwd. bias.

$$V_s = V_o + 2V_D$$

$$\begin{aligned} V_o &= V_s - 2V_D \\ &= V_{sp} \sin \theta - 2V_D \end{aligned}$$

when,  $V_o > 0$ , then current flow  $2I_o$  in

$V_s \rightarrow$  input

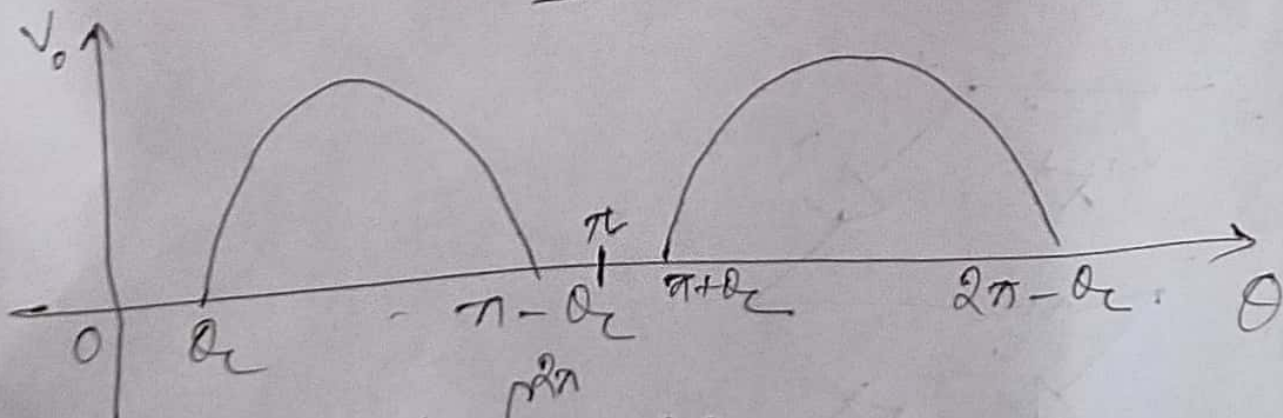
$V_o \rightarrow$  output  $\rightarrow$  m-20 across it

m-10 (20000). 2100  $V_m \approx 0$  210.

$V_{sp} \sin \theta_c \rightarrow$  input voltage starting at  $\theta_c$   
boundary condition

$$V_{sp} \sin \theta_c = 2V_o$$

$$\therefore \theta_c = \sin^{-1} \left( \frac{2V_o}{V_{sp}} \right)$$



$$V_o(\text{avg}) = \frac{1}{2\pi} \int_0^{2\pi} V_o d\theta$$

$$= \frac{2}{2\pi} \int_0^{\pi} V_o d\theta$$

$$= \frac{1}{\pi} \int_{\theta_c}^{\pi - \theta_c} V_o d\theta = \frac{1}{\pi} \int_{\theta_c}^{\pi - \theta_c} (V_{sp} \sin \theta - 2V_o) d\theta$$



$$= \frac{1}{\pi} \left[ V_{sp}(-\cos\theta) - 2V_D\theta \right]_{\theta_1}^{\pi-\theta_c}$$

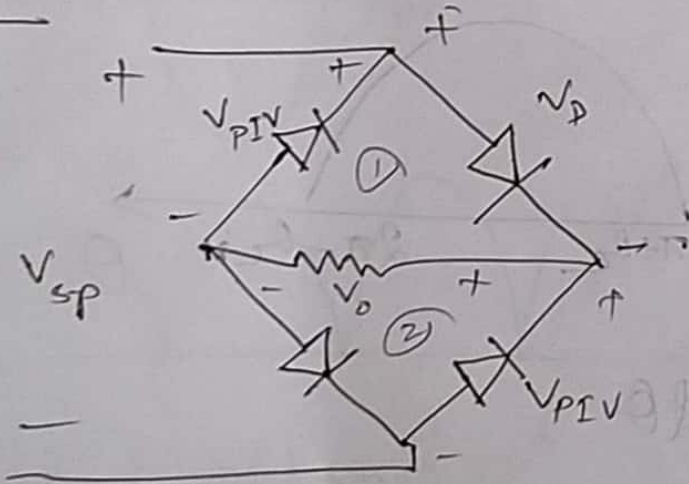
$$\approx \frac{1}{\pi} \int_0^{\pi} (V_{sp}\sin\theta - 2V_D) d\theta$$

$$= \boxed{\frac{2}{\pi} V_{sp} - 2V_D}$$

Now,  
 $\theta_c = \sin^{-1} \left( \frac{2V_D}{V_{sp}} \right)$

~~$2V_D < \theta_c$~~   
 $2V_D > \theta_c$  (assuming  $\theta_c$  very small)

PIV :



$$V_{PIV} = (V_D + V_0)_{\max} \quad [\text{KVL in ①}]$$

$$= (V_D + V_s - 2V_D)_{\max}$$

$$= (V_s - V_D)_{\max}$$

$$= V_{sp} - V_D$$

output peak current/peak current through any diode

$$i_{\text{peak}} = \frac{V_{o,\text{peak}}}{R}$$

$$= \frac{(V_s - 2V_D)_{\text{max}}}{R}$$

$$= \frac{V_{sp} - 2V_D}{R}$$

	$V_o$	PIV	$V_o$ (avg.)	peak current through diode	Total angle per cycle when $V_o = 0$
H.W.	$V_s - V_D$	$V_{sp}$	$\frac{V_{sp}}{\pi} - \frac{V_D}{2}$	$\frac{V_{sp} - V_D}{R}$	$\pi + 2\sin^{-1}\left(\frac{V_D}{V_{sp}}\right)$
FW(CT)	$V_s - V_D$	$2V_{sp} - V_D$	$\frac{2V_{sp}}{\pi} - V_D$	$\frac{V_{sp} - V_D}{R}$	$4\sin^{-1}\left(\frac{V_D}{V_{sp}}\right)$
FW(Bridge)	$V_s - 2V_D$	$V_{sp} - V_D$	$\frac{2V_{sp}}{\pi} - 2V_D$	$\frac{V_{sp} - 2V_D}{R}$	$4\sin^{-1}\left(\frac{2V_D}{V_{sp}}\right)$

Problem: A FW-rectifier circuit with a  $1\text{ k}\Omega$  load operates  $120\text{ V (rms)}$   $60\text{ Hz}$  household supply through a 5 to 1 transformer having a center-tapped secondary winding. It uses 2  $\text{Si}$  diodes that can be modeled to have a  $0.7\text{ V}$  drop of all currents.



